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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/824,060	04/03/2001	Koji Shimazawa	109164	9270
25944 75	590 03/10/2004		EXAM	XAMINER DAVID DONALD
OLIFF & BERRIDGE, PLC			DAVIS, DAVID DONALD	
P.O. BOX 1992	28	,		
ALEXANDRIA, VA 22320			ART UNIT	PAPER NUMBER
			2652	3
			DATE MAILED: 03/10/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

•	· · · · · · · · · · · · · · · · · · ·	Application No.	Applicant(s)		
	•	09/824,060	SHIMAZAWA ET	SHIMAZAWA ET AL.	
	Office Action Summary	Examiner	Art Unit		
		David D. Davis	2652		
	The MAILING DATE of this communication a	appears on the cover sheet	with the correspondence ac	Idress	
Period fo	• •				
THE   - Exte after - If the - If NO - Failu - Any	ORTENED STATUTORY PERIOD FOR REF MAILING DATE OF THIS COMMUNICATION nsions of time may be available under the provisions of 37 CFR SIX (6) MONTHS from the mailing date of this communication. It period for reply specified above is less than thirty (30) days, a report of the period for reply is specified above, the maximum statutory per te to reply within the set or extended period for reply will, by state reply received by the Office later than three months after the material patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may reply within the statutory minimum of od will apply and will expire SIX (6) N tute, cause the application to become	a reply be timely filed thirty (30) days will be considered time IONTHS from the mailing date of this of ABANDONED (35 U.S.C. § 133).	ly. communication.	
1)⊠	Responsive to communication(s) filed on 2	<u> 9 December 2003</u> .			
2a)⊠	This action is <b>FINAL</b> . 2b)	This action is non-final.			
3)□	Since this application is in condition for allo closed in accordance with the practice und			ne merits is	
· _	on of Claims				
•	Claim(s) 1-17 is/are pending in the applicat				
	4a) Of the above claim(s) is/are withd	rawn from consideration.		•	
· <u> </u>	Claim(s) is/are allowed. Claim(s) <u>1-9 and 12-17</u> is/are rejected.				
·	Claim(s) <u>10 and 11</u> is/are objected to.				
· <u> </u>	Claim(s) are subject to restriction and	d/or election requirement			
•	ion Papers	aron ciconom requirement.			
9)🛛	The specification is objected to by the Exami	iner.			
10)	The drawing(s) filed on is/are: a)□ ac	cepted or b) objected to b	y the Examiner.		
	Applicant may not request that any objection to	the drawing(s) be held in ab	eyance. See 37 CFR 1.85(a).		
11)	The proposed drawing correction filed on	is: a)	disapproved by the Examin	er.	
	If approved, corrected drawings are required in				
12) 🗌	The oath or declaration is objected to by the	Examiner.			
Priority (	ınder 35 U.S.C. §§ 119 and 120				
13)⊠	Acknowledgment is made of a claim for fore	eign priority under 35 U.S.0	C. § 119(a)-(d) or (f).		
a)	⊠ All b)  Some * c)  None of:				
	1. Certified copies of the priority docume	ents have been received.			
	2. Certified copies of the priority docume	ents have been received in	Application No		
* 5	3. Copies of the certified copies of the particular application from the International See the attached detailed Office action for a I	Bureau (PCT Rule 17.2(a)	).	Stage	
14)[] <i>A</i>	Acknowledgment is made of a claim for dome	estic priority under 35 U.S.	C. § 119(e) (to a provisiona	l application).	
a	)  The translation of the foreign language   Acknowledgment is made of a claim for dome	provisional application has	been received.	•	
Attachmen	_	• •			
2) 🔲 Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s	5) Notice	ew Summary (PTO-413) Paper No of Informal Patent Application (PT		

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### **DETAILED ACTION**

### Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-9 and 12-17 are rejected under 35 U.S.C. 102(b) as being anticipated by Dill et al (US 5,898,548). As per claim 1, Dill et al shows in figures 4A and 4B a tunnel magnetoresistive effective element includes a ferromagnetic tunnel effective film 100, a magnetic bias means 150, a first conductive layer, and a second conductive layer 104. The ferromagnetic tunnel effective film 100 has a free layer 132, a pinned layer 118 and a tunnel barrier layer 120 sandwiched between the free layer 132 and the pinned layer 118. The magnetic bias means 150 applies a bias magnetic field to the free layer 132. The first conductive layer is formed on one surface of the ferromagnetic tunnel effective film 100 so as to be electrically conducted to the ferromagnetic tunnel effective film 100. The second conductive layer 104 is formed on the other surface of the ferromagnetic tunnel effective film 100 to be electrically conducted to the ferromagnetic tunnel effective film 100. At least one of the first conductive layer and the second conductive layer 104 generate a magnetic field having the same direction as that of the bias magnetic field through a sense current therein.

As per claim 2, the first conductive layer of Dill et al includes a first electrode 102 / magnetic shielding portion S1 and a first leading electrode portion. The first electrode 102/magnetic shielding portion S1 is provided on the one surface of the ferromagnetic tunnel

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effective film 100 and the first leading electrode portion is electrically conducted to a part of the first electrode 102/magnetic shielding portion S1 at a position in which a magnetic field having the same direction as the bias magnetic field is generated by a sense current in the first electrode 102/magnetic shielding portion S1 As per claim 3, the first leading electrode portion of Dill et al, also shown in figures 4A and 4B is electrically conducted to the part of the first electrode 102/magnetic shielding portion S1 at a position, along the bias magnetic field direction, apart from a center line of the ferromagnetic tunnel effective film 100 orthogonal to the bias magnetic field.

As per claim 4, Dill et al additionally shows the second conductive layer 104 includes a second electrode/magnetic shielding portion S2 and a second leading electrode portion, and the second electrode/magnetic shielding portion S2 is provided on the other surface of the ferromagnetic tunnel effective film 100. The second leading electrode portion is electrically conducted to a part of the second electrode/magnetic shielding portion S2 at a position in which a magnetic field having the same direction as that of the bias magnetic field is generated by a sense current in the second electrode/magnetic shielding portion S2.

As per claim 5, Dill et al further shows the second leading electrode portion electrically conducted to the part of the second electrode/magnetic shielding portion S2 at a position, along the bias magnetic field direction, apart from the center line of the ferromagnetic tunnel effective film 100 orthogonal to the bias magnetic field. As per claim 6, the first leading electrode portion and the second leading electrode portion of Dill et al, as shown in figures 4A and 4B are provided in respective different sides from the center line of the ferromagnetic tunnel effective film 100.

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As per claim 7, Dill et al even further shows the first leading electrode portion and the second leading electrode portion provided in either side from the center line of the ferromagnetic tunnel effective film 100. As per claim 8, Dill et al still even further shows in figure 4A and 4B a planer angle of a line segment to a first center point of a boundary line between the first electrode 102/magnetic shielding portion S1 and the first leading electrode portion from a center point of the ferromagnetic tunnel effective film 100 for the bias magnetic field direction or a planer angle of a line segment to a second center point of a boundary line between the second electrode/magnetic shielding portion S2 and the second leading electrode portion from the center point of the ferromagnetic tunnel effective film 100 for the bias magnetic field direction is set to 5 degrees or over.

As per claim 9, Dill et al shows in figures 4A and 4B the magnetic bias means 150 including a bias magnetic field-inductive layer to apply a given bias magnetic field to the free layer 132 of the ferromagnetic tunnel effective film 100 and a magnetic bias applying means to apply a given magnetic field to the bias magnetic field-inductive layer.

As per claim 12, Dill et al shows in figure 3 a thin film magnetic head including at least one reading element composed of a tunnel magnetoresistive effective element as. As per claim 13, Dill et al also shows in figure 3 the thin film magnetic head including at least one writing element. As per claim 14, Dill et al additionally shows in figure 3 that the writing element is composed of an inductive type electromagnetic converting element including a first magnetic film, a second magnetic film and a gap film. The forefronts of the first magnetic film and the second magnetic film are separated by the gap film, thereby to constitute a writing pole portion. As per claim 15, Dill further shows in figure 3 the writing element composed of an inductive

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type electromagnetic converting element including a first magnetic film and a second magnetic film having a main magnetic pole portion to constitute a perpendicular writing pole portion and a supplementary magnetic pole portion to magnetically combine the main magnetic pole portion and the first magnetic film.

As per claim 16, the magnetic head device of Dill also includes a thin film magnetic head and a head supporting device to support the thin film magnetic head. As per claim 17, the magnetic recording drive device of Dill et al additionally includes a magnetic head device and a magnetic disk to be magnetically recorded and reproduced by the magnetic head device.

## Allowable Subject Matter

3. Claims 10 and 11 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

### Response to Arguments

4. Applicant's arguments filed December 29, 2003 have been fully considered but they are not persuasive. In the sentence bridging pages 3 and 4 Applicant states the following: "Nowhere does Dill even mention that the sense current I is polarized in a manner that generates a magnetic field in the same direction as that of the bias magnetic field." This is a curious statement because Dill discloses a tunnel magnetoresistive element as required by the claims and not unlike applicant's invention, and Dill *shows* current I generated magnetic field 133 in the same direction as that of bias magnetic field 151.

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### Conclusion

5. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David D. Davis whose telephone number is (703) 308-1503. The examiner can normally be reached on Monday thru Friday between 9:30-6:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Hoa T. Nguyen can be reached on (703) 305-9687. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David D. Davis Primary Examiner Art Unit 2652

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